

Diode solutions for on-board battery charger (OBC) applications

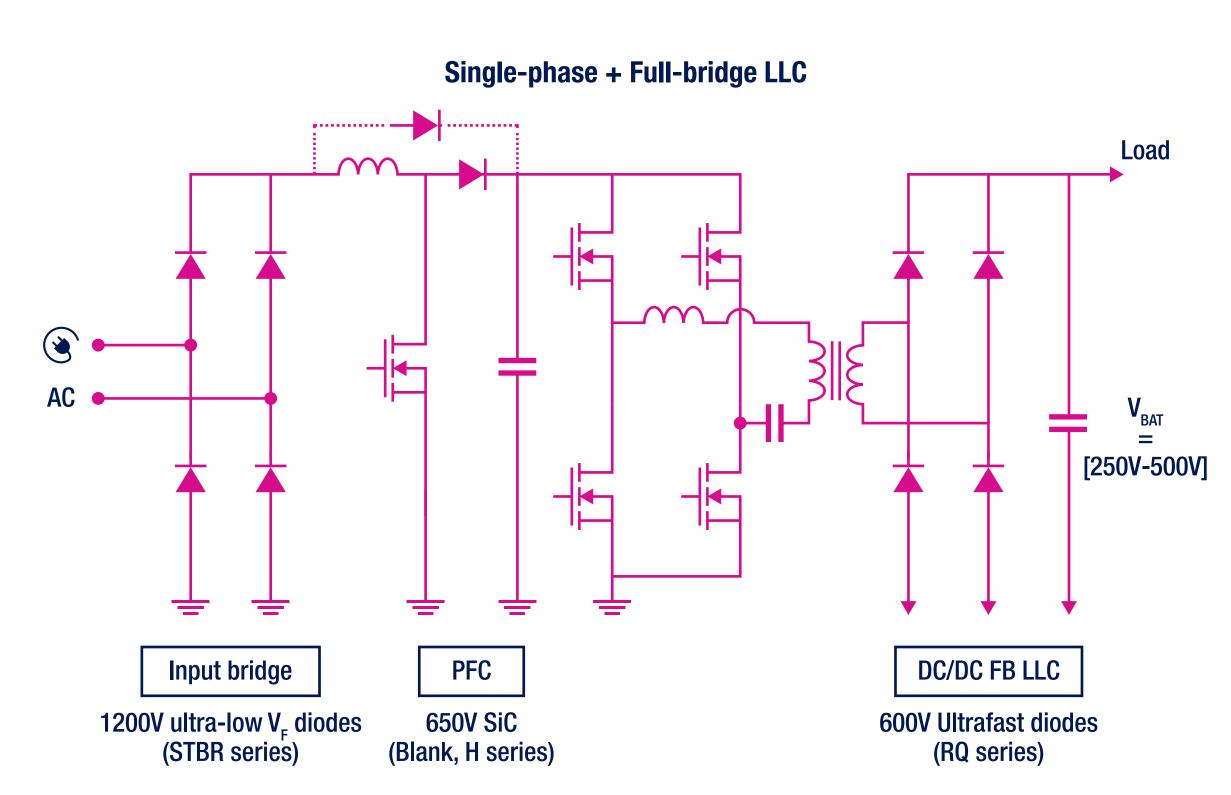
for input bridge, power factor correction and LLC topologies

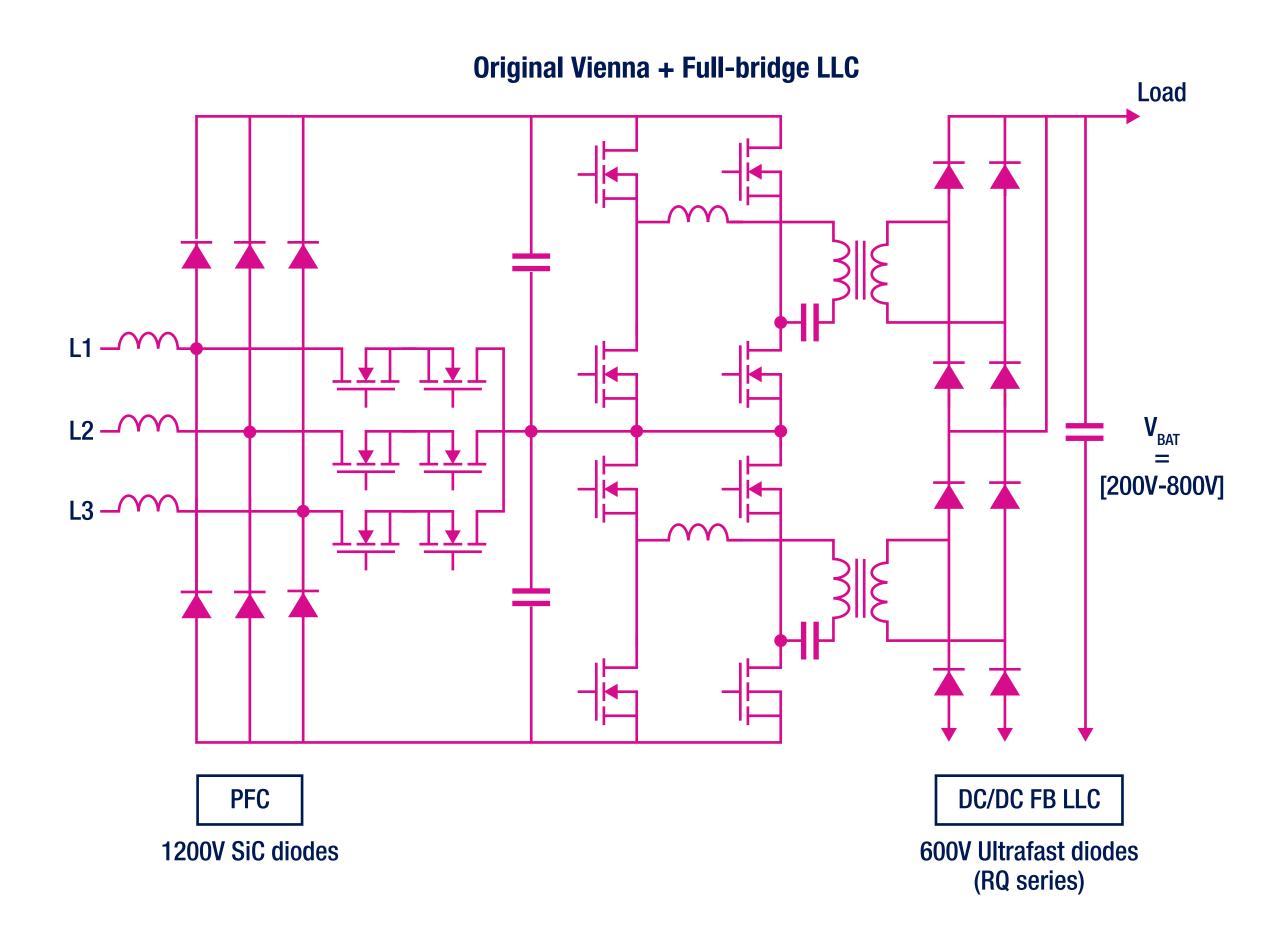
ABSTRACT

ST offers diode solutions for on-board battery charger (OBC) and charging station applications based on several common topologies:

- For input bridge: Our new 1200V STBR bridge rectifier diode provides ultra low V_F with very high robustness (I_{FSM} and ESD).
- For power factor correction (PFC): SiC diodes remain the best choice for high switching frequencies.
- For full-bridge LLC: Our new DC/DC 600V RQ series is the most suitable solution for high efficiency with optimized V_F/Q_{RR} trade off.

TOPOLOGIES





FEATURES AND BENEFITS

1200V STBR diodes for input bridge:

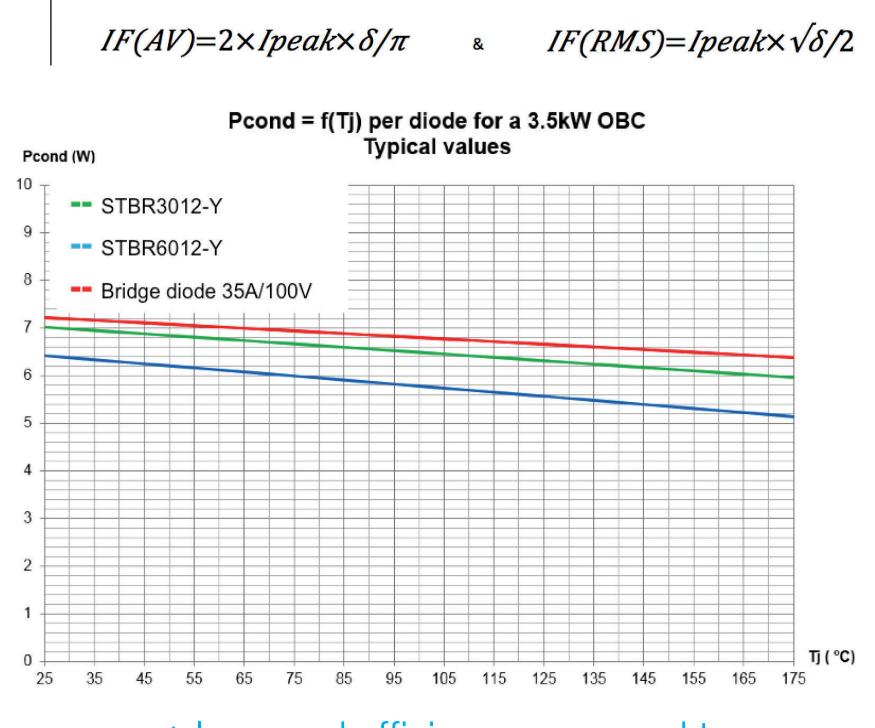
- Ultra low V_F
- High I_{ESM}
- Products available in SMD & TH packages
- $V_{RRM} = 600V @ -40 °C (< > 650V @ 25 °C)$ to be compliant with load dump test

650V and 1200V SiC diodes for PFC:

- 650V and 1200V SiC with mature technology
- Lowest V_□ in the market
- Optimized I_{ESM}
- Wide range of packages

600V ultrafast diode for DC-DC:

- Optimized V_F/Q_{RR} trade-off to cover wide range of output voltage and output current
- Soft behavior for good EMI results
- $V_{RRM} = 600V @ -40 °C (< > 650V @ 25 °C)$ to be compliant with load dump test



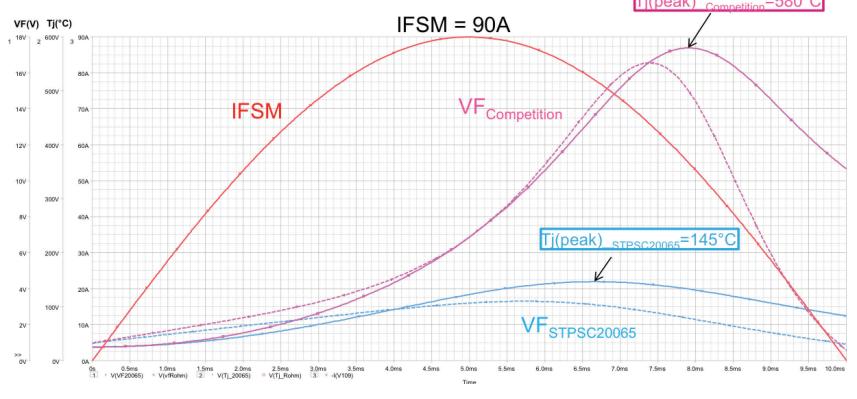
→ Improved efficiency compared to standard bridge diodes

Bridge

A STBR3012WY
STBR6012WY

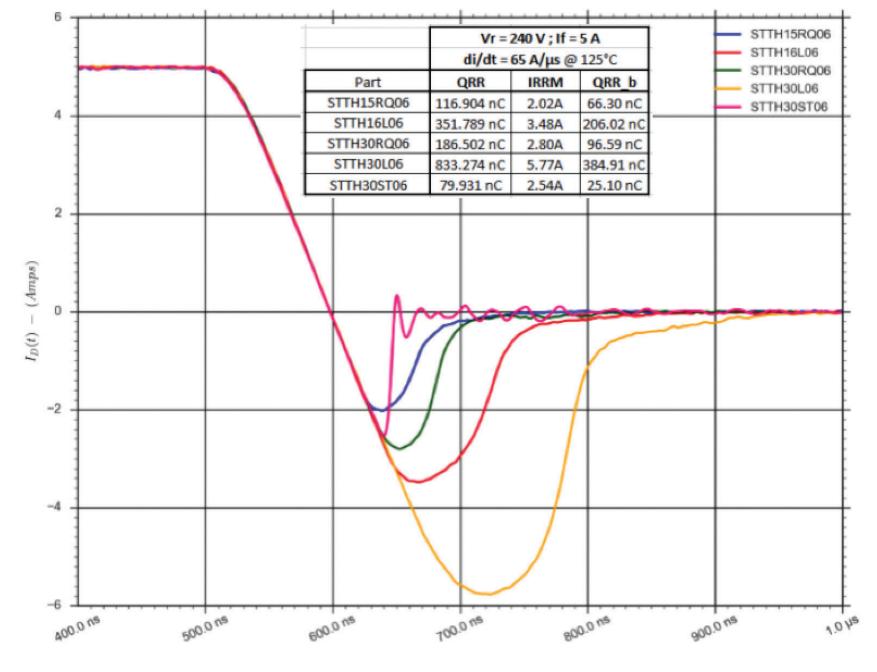
PFC
STPSC20065DY
STPSC12065DY
STPSC20H065C-Y
STPSC10H12DY
STPSC20H12DY

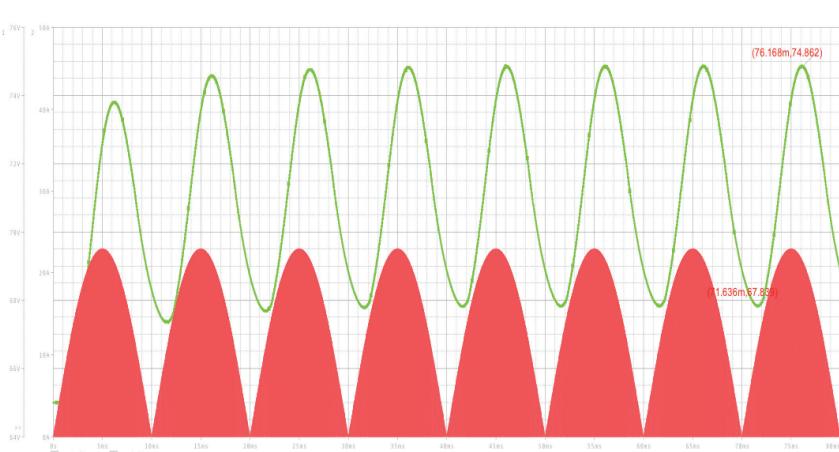
DC-DC full-bridge LLC STTH15RQ06-Y STTH30RQ06-Y



- → During high current surges, the V_F is clamped and the temperature is controlled to avoid thermal runaway phenomena
- → ST SiC diodes present the new reference V_r to reach the highest overall efficiency







→ Good performance in secondary side of a LLC resonant topology used in OBC applications.